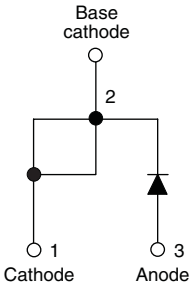
Fast Soft Recovery Rectifier Diode, 10 A

TO-220AC FULL-PAK



FEATURES/DESCRIPTION

Available
RoHS* COMPLIANT

The 10ETF06FPPbF fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

The fully isolated package (V_{INS} = 2500 V_{RMS}) is UL E78996 approved.

This product series has been designed and qualified for industrial level and lead (Pb)-free.

APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

PRODUCT SUMMARY	
V_{RRM}	200 to 600 V
V_F at 10 A	< 1.2 V
t_{rr}	50 ns

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
V_{RRM}		200 to 600	V
$I_{F(AV)}$	Sinusoidal waveform	10	A
I_{FSM}		150	
t_{rr}	1 A, 100 A/µs	50	ns
V_F	10 A, T_J = 25 °C	1.2	V
T_J		- 40 to 150	°C

VOLTAGE RATINGS			
PART NUMBER	V_{RRM}, MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 °C mA
10ETF02FPPbF	200	300	2
10ETF04FPPbF	400	500	
10ETF06FPPbF	600	700	

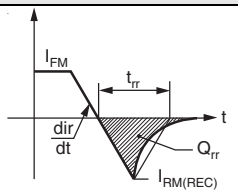
ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	T_C = 98 °C, 180° conduction half sine wave	10	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	150	
		10 ms sine pulse, no voltage reapplied	160	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	112.5	A^2s
		10 ms sine pulse, no voltage reapplied	160	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reapplied	1600	$A^2\sqrt{s}$

* Pb containing terminations are not RoHS compliant, exemptions may apply

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	10 A, T_J = 25 °C		1.2	V
Forward slope resistance	r_t	T_J = 150 °C		23.5	mΩ
Threshold voltage	$V_{F(TO)}$			0.85	V
Maximum reverse leakage current	I_{RM}	T_J = 25 °C	V_R = Rated V_{RRM}	0.1	mA
		T_J = 150 °C		3.0	

RECOVERY CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Reverse recovery time	t_{rr}	I_F at 10 Apk 25 A/µs 25 °C	145	ns	
Reverse recovery current	I_{rr}		2.75	A	
Reverse recovery charge	Q_{rr}		0.32	µC	
Snap factor	S		0.6		

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T_J, T_{Stg}		- 40 to 150	°C
Maximum thermal resistance junction to case		R_{thJC}	DC operation	2.5	°C/W
Maximum thermal resistance junction to ambient		R_{thJA}		62	
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device			Case style TO-220AC FULL-PAK (94/V0)	10ETF06FP	

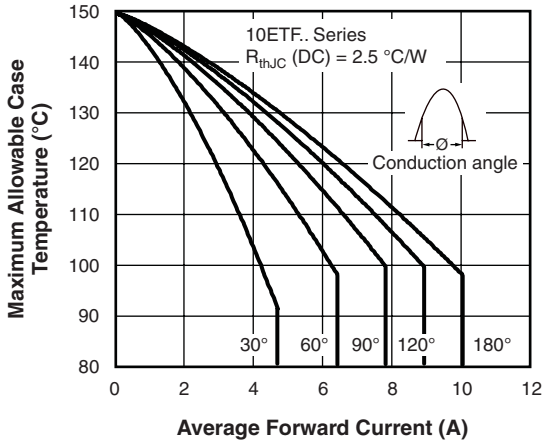


Fig. 1 - Current Rating Characteristics

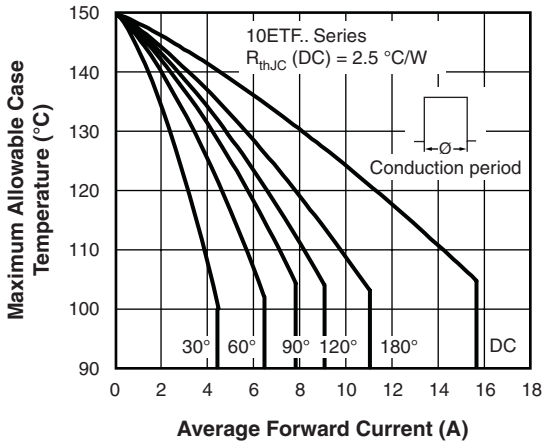


Fig. 2 - Current Rating Characteristics

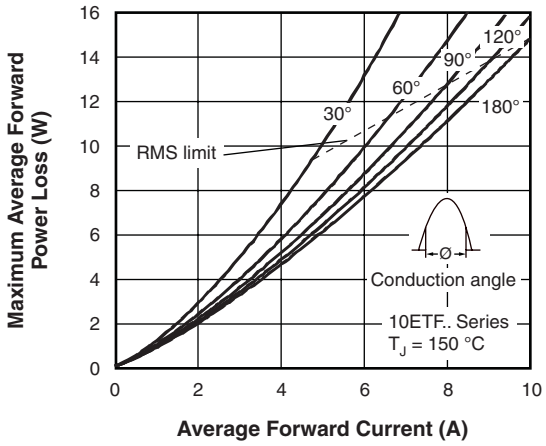


Fig. 3 - Forward Power Loss Characteristics

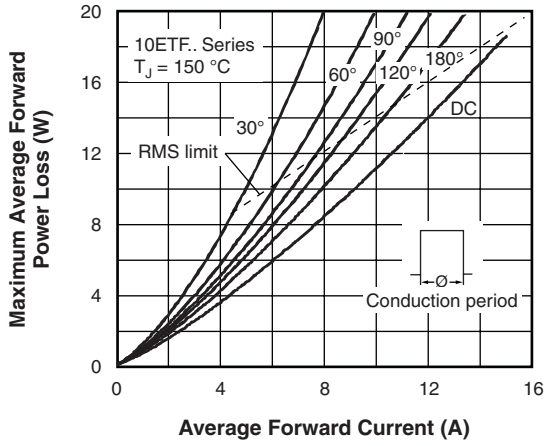


Fig. 4 - Forward Power Loss Characteristics

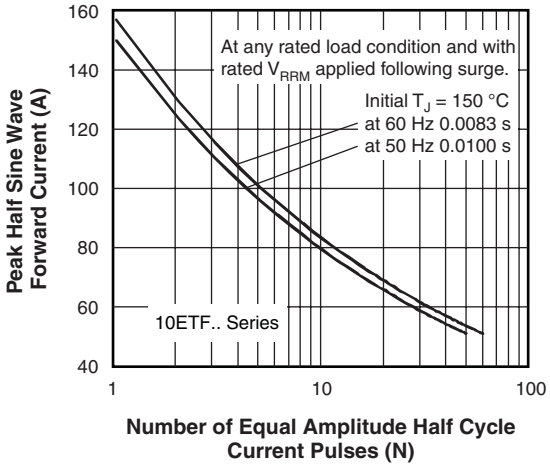


Fig. 5 - Maximum Non-Repetitive Surge Current

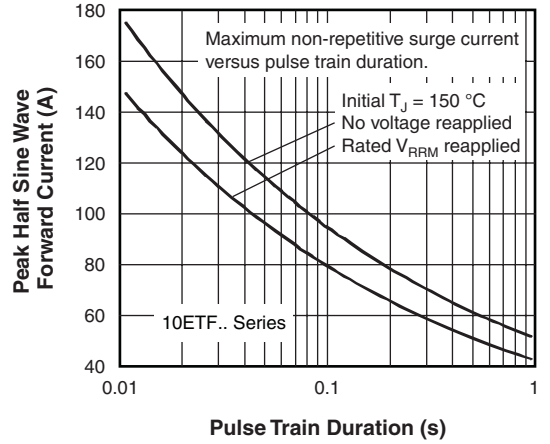


Fig. 6 - Maximum Non-Repetitive Surge Current

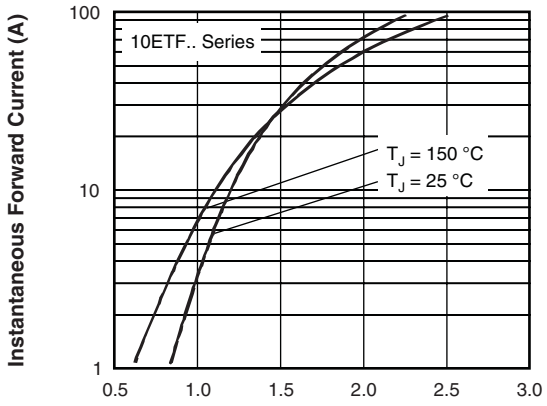


Fig. 7 - Forward Voltage Drop Characteristics

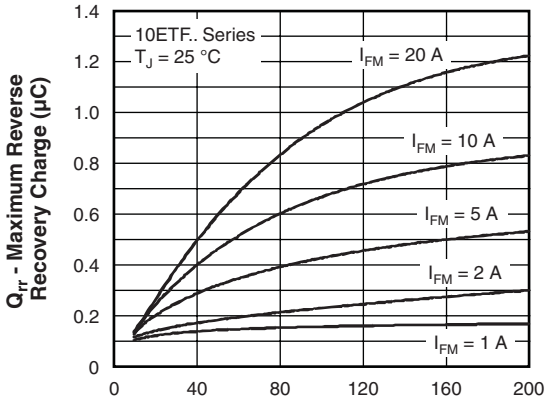


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

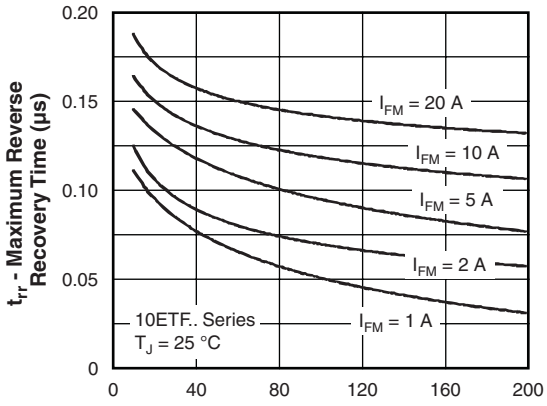


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

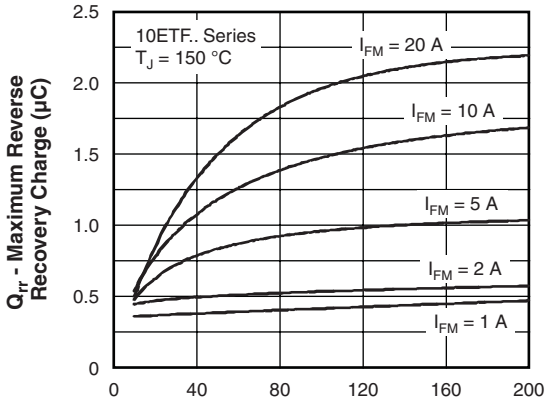


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

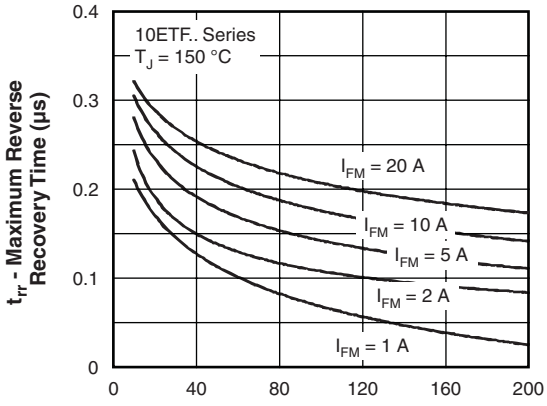


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

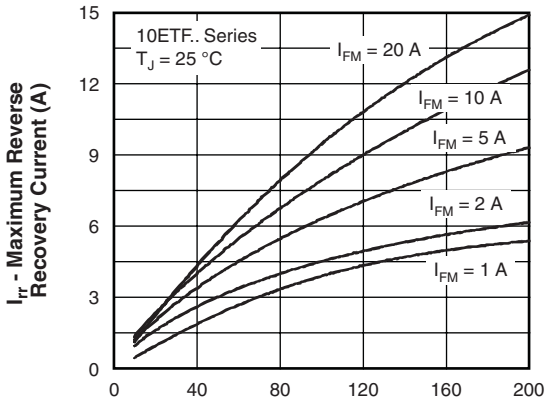


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

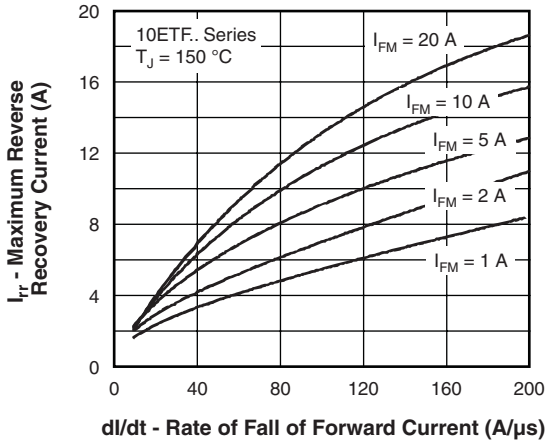


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

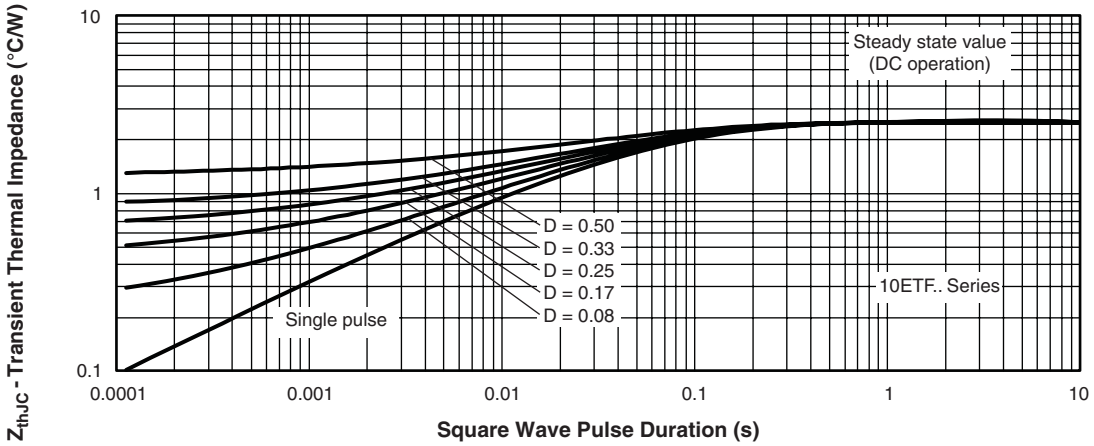


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code

10	E	T	F	06	FP	PbF
1	2	3	4	5	6	7

1 - Current rating (10 = 10 A)

2 - Circuit configuration:
E = Single diode

3 - Package:
T = TO-220AC

4 - Type of silicon:
F = Fast soft recovery rectifier

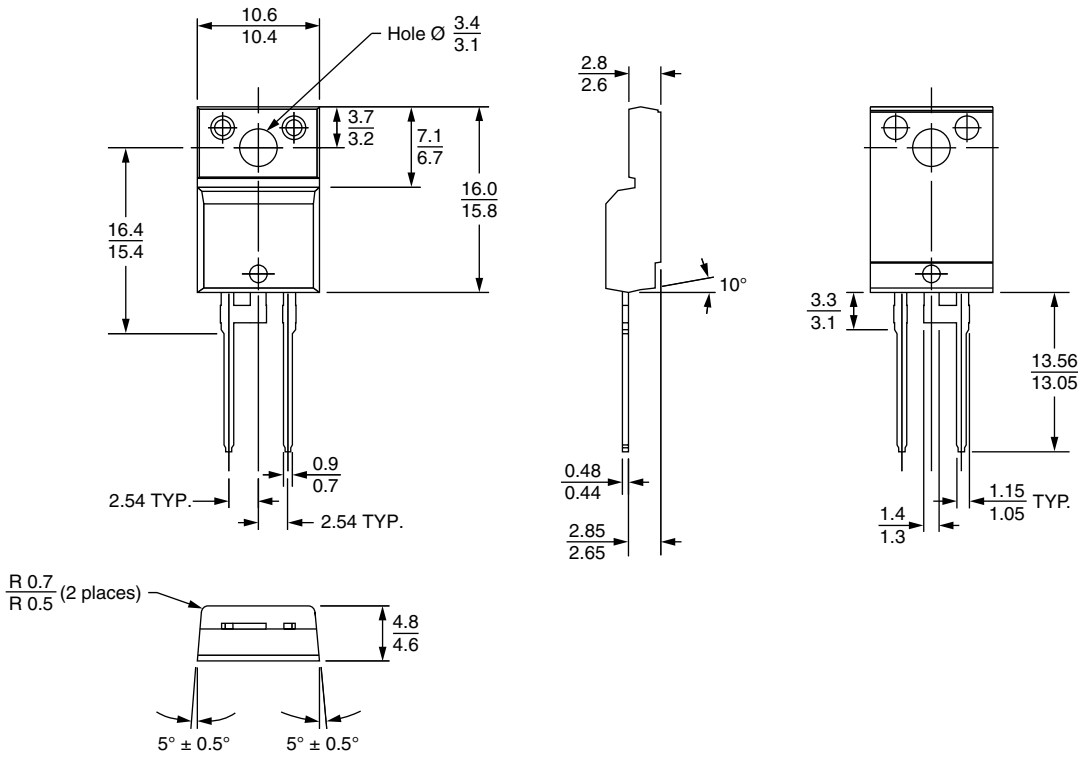
5 - Voltage code x 100 = V_{RRM}
02 = 200 V
04 = 400 V
06 = 600 V

6 - FULL-PAK

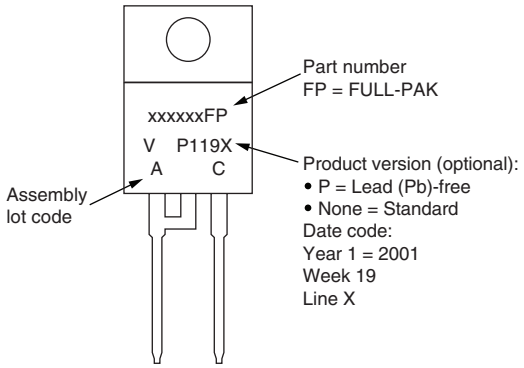
7 - • None = Standard production
• PbF = Lead (Pb)-free

TO-220AC FULL-PAK

DIMENSIONS in millimeters



TO-220AC FULL-PAK



Example: This is a xxxxxxFP with assembly lot code AC, assembled on WW 19, 2001 in the assembly line “X”

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